CURRICULUM

| Master study program | FIZICA MATERIALELOR AVANSATE ȘI NANOSTRUCTURI/PHYSICS OF ADVANCED MATERIALS AND NANOSTRUCTURES |
|---|--|
| Academic field | PHYSICS |
| Faculty | FACULTY OF PHYSICS |
| Duration | 2 years (4 semesters) |
| Type of study | full-time (IF) |
| full-time(IF)/ part-time (IFR)/ distance-learning (ID) | |

1. STRUCTURE OF ACADEMIC YEAR

Number of semesters: 2/year (4/program) Number of ECTS: 30/semester Number of face-to-face activities/week: 22-24 Structure of academic year (in weeks):

| | Face-to-fa | ce learning | I | Exam session | on | Research | Holidays | | | | | |
|------------|------------|-------------|--------|--------------|---------|-----------------|----------|--------|--------|--|--|--|
| | 1-st sem. | II-nd sem. | Winter | Summer | Re-exam | intern- ship | Winter | Spring | Summer | | | |
| 1-st year | 14 | 14 | 3 | 4 | 3 | 0 | 3 | 1 | 9 | | | |
| II-nd year | 14 | 10+4 | 3 | 3 | 2 | 0 | 3 | 1 | | | | |

2. FLEXIBILITY OF STUDY ROUTE

Flexible study routes are insured by elective and optional courses/disciplines. Elective disciplines are proposed in each year. In the case of optional (facultative) courses, corresponding supplementary credits (ECTS) are added to the academic record (diploma supplement). Credits for optional courses are obtained after passing a form of examination, as defined in the course information sheet. Credits corresponding to optional courses cannot substitute for credits corresponding to compulsory courses.

3. STUDY PROGRESS REQUIREMENTS

Requirements for passing a year of study are defined in the *Rules and Regulations regarding proffessional activity of students* adopted by the Senate of the University of Bucharest.

4. FINAL EXAM

Finalization of master thesis: 4-th semester

Master's thesis defense session: june, after 4-th semester

Number of credits for final exam: 10 credits (for defending master thesis) in addition to compulsory 120 credits.

5. SYLLABUS

UNIVERSITY OF BUCHAREST, FACULTY OF PHYSICS Field of study: PHYSICS MASTER PROGRAM: PHYSICS OF ADVANCED MATERIALS AND NANOSTRUCTURES Accredited: 2013 / Revised: 2019 Applies begining with: autumn 2020 Type of study: full-time Duration of study: 4 semesters/120 ECTS

SYLLABUS

Academic year 2020-2021

1-st year

C = course; L = laboratory; T = tutorial; P = research project; E = exam; CL = colloquium; A = assessment; ECTS = number of credits; DI.xxx = compulsory course; DO.xxx = elective course, DFC.xxx = optional/facultative course; DA = knowledge-deepening course; DS = course of advanced knowledge in the field of study program; SI = number of hours of individual study

| Crt. | Code | Course | 1-st semester | | | | | | | 2 | Туре | SI | | | | |
|------|----------|--|---------------|---|---|---|----|----------|----|---|------|----|---|----------|----|----|
| no. | | | С | S | L | Р | A | EC TS | С | S | L | Р | A | EC TS | 1 | |
| 1 | DI.101 | Quantum statistical physics | 2 | 2 | 0 | 0 | Е | 6 | - | - | - | - | - | - | DA | 90 |
| 2 | DI.102 | Condensed state physics | 2 | 2 | 0 | 0 | Е | 6 | - | - | - | - | - | - | DS | 90 |
| 3 | DI.103 | Group theory and application to physics | 2 | 2 | 0 | 0 | Е | 6 | - | - | - | - | - | - | DA | 90 |
| 4 | DI.104 | Experimental methods in physics | 2 | 0 | 3 | 0 | Е | 6 | - | - | - | - | - | - | DA | 76 |
| 5 | DI.105 | Ethics and academic integrity | 1 | 0 | 0 | 0 | CL | 3 | - | - | - | - | - | - | DS | 57 |
| 6 | DI.106 | Research activity (traineeship) | 0 | 0 | 0 | 4 | V | 3 | - | - | - | - | - | - | DA | 15 |
| 7 | DI.107 | Materials characterization techniques | - | - | - | - | - | - | 2 | 0 | 2 | 0 | E | 6 | DS | 90 |
| 8 | DI.108 | Magnetism. Spintronics | - | - | - | - | - | - | 2 | 1 | 1 | 0 | E | 5 | DA | 65 |
| 9 | DI.109 | Organic semiconductors and applications | - | - | - | - | - | - | 2 | 0 | 2 | 0 | E | 6 | DS | 90 |
| 10 | DI.110 | Preparation methods for nanomaterials and nanostructures | - | - | - | - | - | - | 2 | 0 | 2 | 0 | E | 5 | DA | 65 |
| | DO.111.1 | Physics of mesoscopic systems | | | | | | | | | | | | | | |
| 11 | DO.111.2 | Transport phenomena in disordered materials | - | - | - | - | - | - | 2 | 2 | 0 | 0 | E | 5 | DS | 65 |
| | DO.111.3 | Linear response theory | | | | | | | | | | | | | | |
| 12 | DI.112 | Research activity (traineeship) | - | - | - | - | - | - | 0 | 0 | 0 | 4 | V | 3 | DA | 15 |
| | | Total | 9 | 6 | 3 | 4 | | 30 | 10 | 3 | 7 | 4 | | 30 | | |
| 13 | DFC.113 | Phase transitions in condensed matter | - | - | - | - | - | - | 2 | 2 | 0 | 0 | Е | 4 | DA | 40 |
| 14 | DFC.114 | Interaction of laser radiation with matter | - | - | - | - | - | - | 2 | 2 | 0 | 0 | Е | 4 | DA | 40 |

Academic year 2021-2022 2-nd year

C = course; L = laboratory; T = tutorial; P = research project; E = exam; CL = colloquium; A = assessment; ECTS = number of credits; DI.xxx = compulsory course; DO.xxx = elective course, DFC.xxx = optional/facultative course; DA = knowledge-deepening course; DS = course of advanced knowledge in the field of study program; SI = number of hours of individual study

| Crt. | Code | Course | 1-st semester | | | | | | | 2- | Туре | SI | | | | |
|--------------------------|----------|-----------------------------------|---------------|---|---|---|-----|----------|----------|----|------|----|----|----------|----|-----|
| no. | | | С | S | L | Р | A | EC TS | С | S | L | Р | A | EC TS | | |
| 1 | DO.201.1 | Nonlinear optics | 2 | 0 | 2 | 0 | Б | 6 | | | | | | | סס | 00 |
| | DO.201.2 | Physics of dielectric materials | 2 | 0 | 2 | 0 | Ľ | 0 | - | - | - | - | - | - | D3 | 30 |
| | DO.202.1 | Computational methods for | | | | | | | | | | | | | | |
| | | electronic structure of materials | 2 | 2 | | 0 | Б | 6 | | | | | | | DA | 90 |
| 2 | DO.202.2 | Advanced methods in statistical | 2 | 2 | | | L L | | - | - | - | - | - | - | DA | 90 |
| | | physics | | | | | | | | | | | | | | |
| 3 | DI.203 | Nanostructures for electronics | 2 | 0 | 2 | 0 | Б | C | | | | | | | DA | 00 |
| | | and optoelectronics | 2 | | 2 | | E | 6 | - | - | - | - | - | - | DA | 90 |
| 4 | DO.204.1 | Physics of semiconductor | | | | | | | | | | | | | | |
| | | devices | | | | | | | | | | | | | | |
| | DO.204.2 | Electrical and optical | 2 | 0 | 2 | 0 | E | 6 | - | - | - | - | - | - | DA | 90 |
| | | characterization of semicon- | | | | | | | | | | | | | | |
| | | ductors | | | | | | | | | | | | | | |
| 5 | DI.205 | Research activity (traineeship) | 0 | 0 | 0 | 6 | V | 6 | - | - | - | - | - | - | DA | 62 |
| 6 | DI.206 | Physics of liquid crystals and | | | | | | | 2 | 0 | 2 | 0 | Б | | DA | 01 |
| | | polymeric materials | - | - | - | - | - | - | 2 | 0 | 2 | 0 | E | 5 | DA | 01 |
| 7 | DO.207.1 | Special electronic and | | | | | | | | | | | | | | |
| | | optoelectronic devices | | | | | | | <u>_</u> | | 2 | 0 | Б | | DC | 01 |
| | DO.207.2 | Physics and technology of thin |] - | - | - | - | - | - | 2 | | 2 | 0 | | 5 | D5 | 81 |
| | | films | | | | | | | | | | | | | | |
| 8 | DI.208 | Research activity (traineeship) | - | - | - | - | - | - | 0 | 0 | 0 | 18 | V | 15 | DA | 191 |
| 9 | DI.209 | Finalization of master thesis | - | - | - | - | - | - | 0 | 0 | 0 | 0 | V | 5 | DA | 121 |
| Total | | 8 | 2 | 6 | 6 | | 30 | 4 | 0 | 4 | 18 | | 30 | | | |
| Defense of master thesis | | - | - | - | - | - | - | - | - | - | - | - | 10 | | | |
| 10 | DFC.210 | Computational methods in | 2 | 2 | 0 | 0 | Б | 2 | | | | | | | DA | 15 |
| | | condensed matter | 2 | | | 0 | | 3 | | | | _ | | | DA | 15 |
| 11 | DFC.211 | Virtual instrumentation and data | 2 | 0 | 2 | 0 | Б | 2 | | | | | | | DA | 1 |
| | | acquisition | 2 | | 2 | | | 3 | - | - | - | - | - | - | DA | 12 |